

PS2502-1X, PS2502-2X, PS2502-4X
 PS2502-1, PS2502-2, PS2502-4



ISOCOM
 COMPONENTS

**HIGH DENSITY MOUNTING
 PHOTODARLINGTON OPTICALLY
 COUPLED ISOLATORS**



APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form :-
 - STD
 - G form
 - SMD approved to CECC 00802
- Certified to EN60950 by the following
 Test Bodies :-
 Nemko - Certificate No. P01102465
 Fimko - Certificate No. FI18162
 Semko - Reference No. 0202041/01-25
 Demko - Certificate No. 311161-01
- BSI approved - Certificate No. 8001

DESCRIPTION

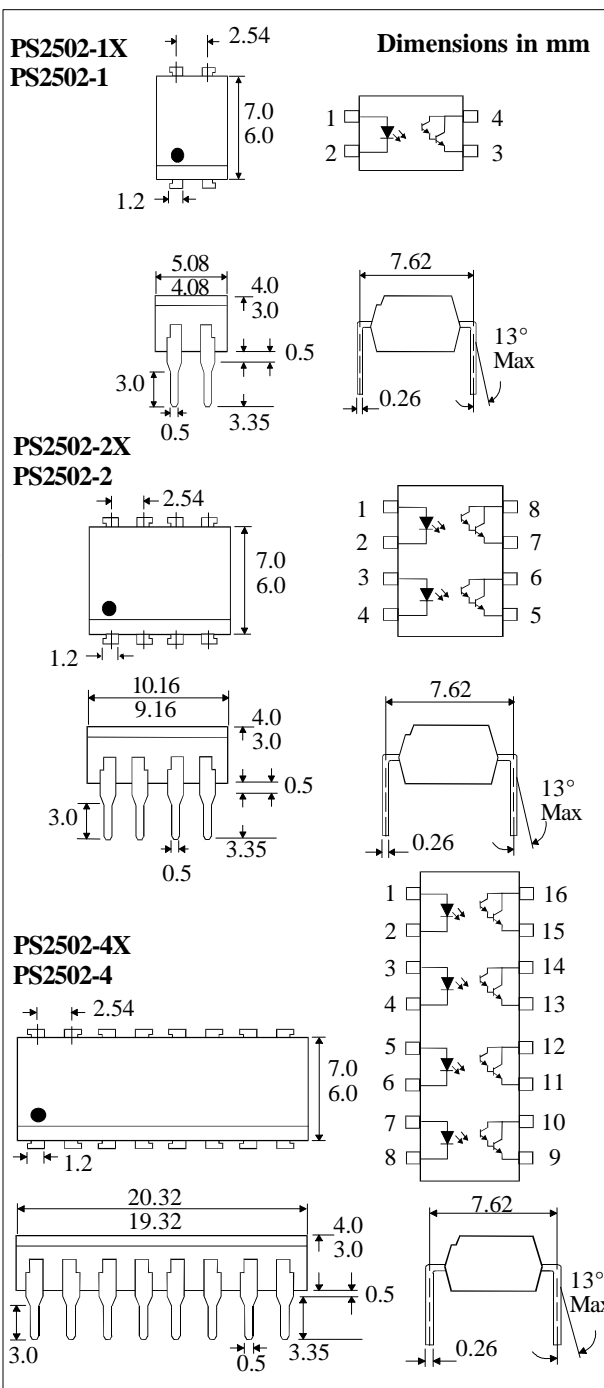
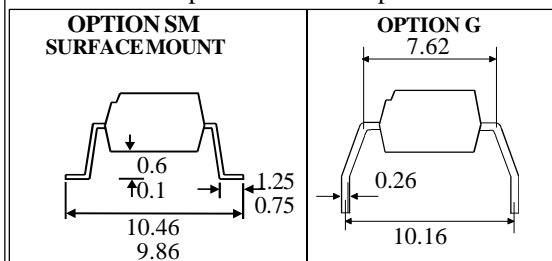
The PS2502-1, PS2502-2, PS2502-4 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photodarlington in space efficient dual in line plastic packages.

FEATURES

- Options :-
 10mm lead spread - add G after part no.
 Surface mount - add SM after part no.
 Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio (200%min)
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature _____ -55°C to + 125°C
 Operating Temperature _____ -30°C to +100°C
 Lead Soldering Temperature
 (1/16 inch (1.6mm) from case for 10 secs) 260°C

INPUT DIODE

Forward Current _____ 50mA
 Reverse Voltage _____ 6V
 Power Dissipation _____ 70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO} _____ 40V
 Emitter-collector Voltage BV_{ECO} _____ 6V
 Power Dissipation _____ 150mW

POWER DISSIPATION

Total Power Dissipation _____ 200mW
 (derate linearly 2.67mW/°C above 25°C)

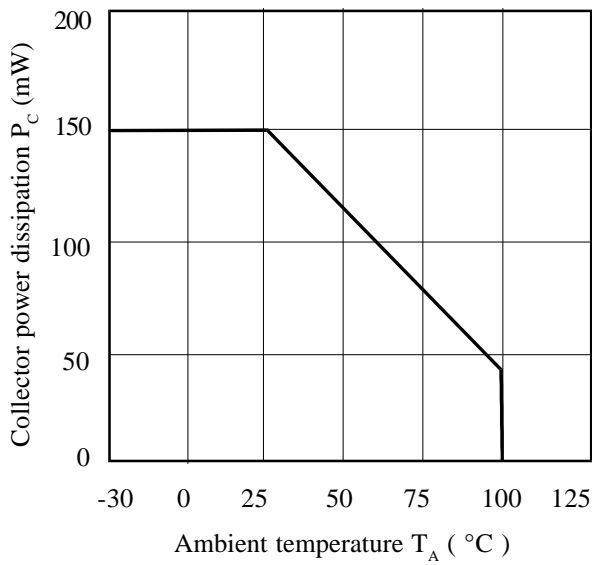
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.4	V	$I_F = 10\text{mA}$
	Reverse Current (I_R)			10	μA	$V_R = 4\text{V}$
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	40			V	$I_C = 0.5\text{mA}$
	Emitter-collector Breakdown (BV_{ECO})	6			V	$I_E = 100\mu\text{A}$
Coupled	Current Transfer Ratio (CTR) (Note 2)	200	2000		%	$1\text{mA } I_F, 2\text{V } V_{CE}$
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			1.0	V	$1\text{mA } I_F, 2\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)
	Output Rise Time t_r Output Fall Time t_f		60 53	300 250	μs μs	$V_{CE} = 2\text{V}$, $I_C = 10\text{mA}, R_L = 100\Omega$

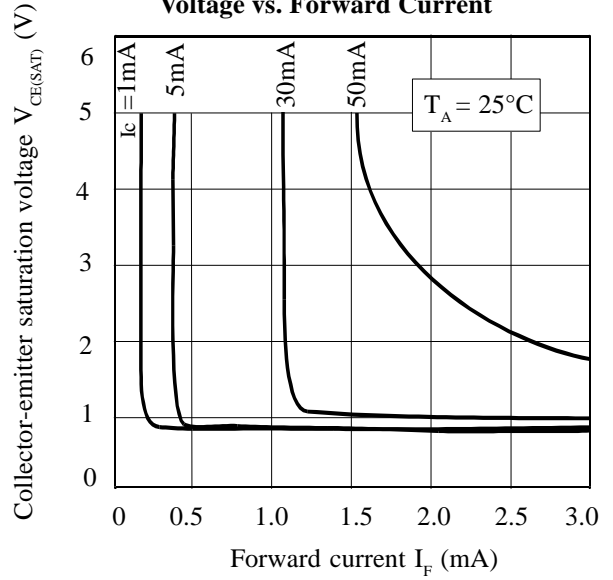
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

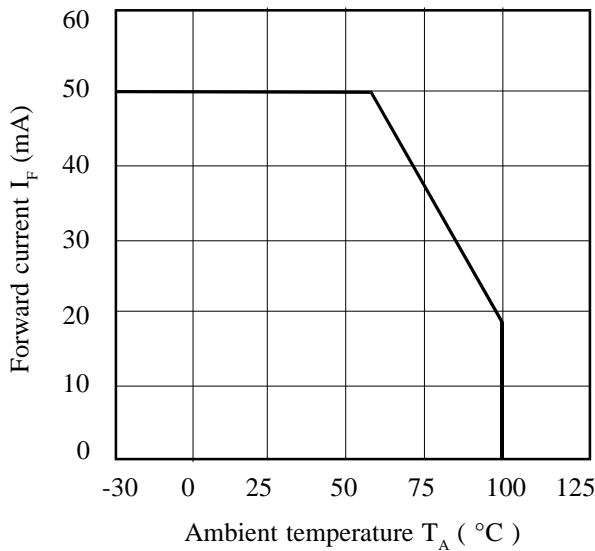
Collector Power Dissipation vs. Ambient Temperature



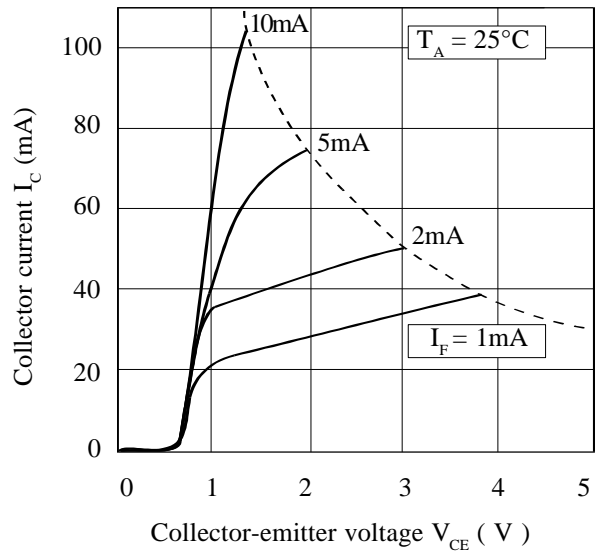
Collector-emitter Saturation Voltage vs. Forward Current



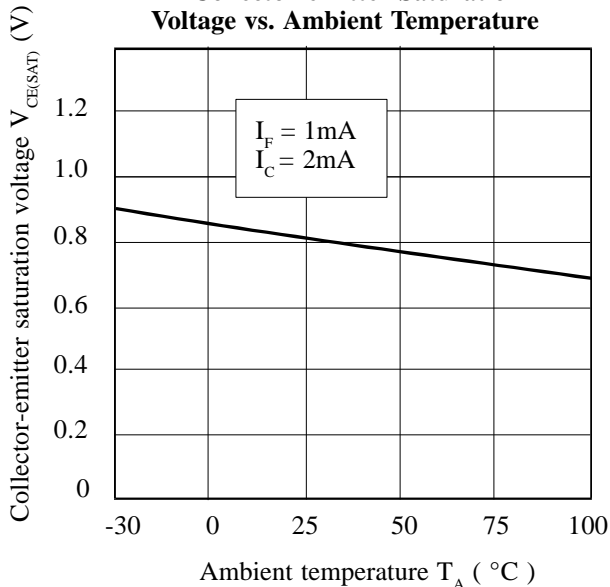
Forward Current vs. Ambient Temperature



Collector Current vs. Collector-emitter Voltage



Collector-emitter Saturation Voltage vs. Ambient Temperature



Relative Current Transfer Ratio vs. Ambient Temperature

